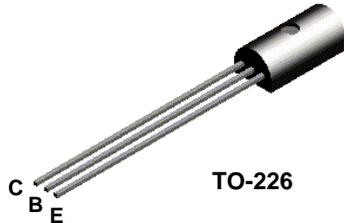


## TN2219A



### NPN General Purpose Amplifier

This device is for use as a medium power amplifier and switch requiring collector currents up to 500 mA. Sourced from Process 19. See PN2222A for characteristics.

#### Absolute Maximum Ratings\*

TA = 25°C unless otherwise noted

Symbol	Parameter	Value	Units
V <sub>CEO</sub>	Collector-Emitter Voltage	40	V
V <sub>CBO</sub>	Collector-Base Voltage	75	V
V <sub>EBO</sub>	Emitter-Base Voltage	6.0	V
I <sub>C</sub>	Collector Current - Continuous	1.0	A
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 to +150	°C

\*These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

#### NOTES:

- 1) These ratings are based on a maximum junction temperature of 150 degrees C.
- 2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

#### Thermal Characteristics

TA = 25°C unless otherwise noted

Symbol	Characteristic	Max	Units
		TN2219A	
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	1.0	W
		8.0	mW/°C
R <sub>θJC</sub>	Thermal Resistance, Junction to Case	125	°C/W
R <sub>θJA</sub>	Thermal Resistance, Junction to Ambient	50	°C/W

# NPN General Purpose Amplifier

(continued)

TN2219A

## Electrical Characteristics

TA = 25°C unless otherwise noted

Symbol	Parameter	Test Conditions	Min	Max	Units
<b>OFF CHARACTERISTICS</b>					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage*	$I_C = 10 \text{ mA}, I_B = 0$	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	$I_C = 10 \text{ } \mu\text{A}, I_E = 0$	75		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	$I_E = 10 \text{ } \mu\text{A}, I_C = 0$	6.0		V
$I_{CEX}$	Collector Cutoff Current	$V_{CE} = 60 \text{ V}, V_{EB(OFF)} = 3.0 \text{ V}$		10	nA
$I_{CBO}$	Collector Cutoff Current	$V_{CB} = 60 \text{ V}, I_E = 0$ $V_{CB} = 60 \text{ V}, I_E = 0, T_A = 150^\circ\text{C}$		10 10	nA $\mu\text{A}$
$I_{EBO}$	Emitter Cutoff Current	$V_{EB} = 3.0 \text{ V}, I_C = 0$		10	nA
$I_{BL}$	Base Cutoff Current	$V_{CE} = 60 \text{ V}, V_{EB(OFF)} = 3.0$		20	nA

## ON CHARACTERISTICS

$h_{FE}$	DC Current Gain	$I_C = 0.1 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 150 \text{ mA}, V_{CE} = 10 \text{ V}$ $I_C = 150 \text{ mA}, V_{CE} = 1.0 \text{ V}$ $I_C = 500 \text{ mA}, V_{CE} = 10 \text{ V}$	35 50 75 100 50 40	300	
$V_{CE(sat)}$	Collector-Emitter Saturation Voltage*	$I_C = 150 \text{ mA}, I_B = 15 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 50 \text{ mA}$		0.3 1.0	V V
$V_{BE(sat)}$	Base-Emitter Saturation Voltage*	$I_C = 150 \text{ mA}, I_B = 1.0 \text{ mA}$ $I_C = 500 \text{ mA}, I_B = 5.0 \text{ mA}$	0.6	1.2 2.0	V V

## SMALL SIGNAL CHARACTERISTICS

$C_{obo}$	Output Capacitance	$V_{CB} = 10 \text{ V}, I_E = 0, f = 100 \text{ kHz}$		8.0	pF
$C_{ibo}$	Input Capacitance	$V_{EB} = 0.5 \text{ V}, I_C = 0, f = 100 \text{ kHz}$		25	pF
$h_{fe}$	Small-Signal Current Gain	$I_C = 1.0 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$ $I_C = 10 \text{ mA}, V_{CE} = 10 \text{ V}, f = 1.0 \text{ kHz}$	50 75	300 375	
$rb'C_C$	Collector Base Time Constant	$I_E = 20 \text{ mA}, V_{CB} = 20 \text{ V}, f = 31.8 \text{ MHz}$		150	pS
NF	Noise Figure	$I_C = 100 \text{ } \mu\text{A}, V_{CE} = 10 \text{ V},$ $R_S = 1.0 \text{ k}\Omega, f = 1.0 \text{ kHz}, B_W = 1.0 \text{ Hz}$		4.0	dB
$Re(h_{ie})$	Real Part of Common-Emitter High Frequency Input Impedance	$I_C = 20 \text{ mA}, V_{CE} = 20 \text{ V}, f = 300 \text{ MHz}$		60	$\Omega$

## SWITCHING CHARACTERISTICS

$t_d$	Delay Time	$V_{CC} = 30 \text{ V}, V_{BE(OFF)} = 0.5 \text{ V},$		10	ns
$t_r$	Rise Time	$I_C = 150 \text{ mA}, I_{B1} = 15 \text{ mA}$		25	ns
$t_s$	Storage Time	$V_{CC} = 30 \text{ V}, I_C = 150 \text{ mA},$		225	ns
$t_f$	Fall Time	$I_{B1} = I_{B2} = 15 \text{ mA}$		60	ns

\*Pulse Test: Pulse Width  $\leq 300 \text{ } \mu\text{s}$ , Duty Cycle  $\leq 2.0\%$

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